

## **SSCN8050SGS6**

### **High Frequency High Gain NPN Power BJT**

#### Features

VCB	VCE	VEB	IC
40V	25V	5V	1.5A

### > Description

This device is produced with advanced high carrier density technology, which is especially used to minimize saturation voltage drop. This device particularly suits low voltage applications such as portable equipment, power management and other battery powered circuits, and low in-line power dissipation are needed in a very small outline surface mount package. Excellent thermal and electrical capabilities.

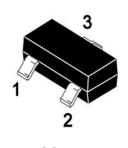
### Applications

- Supply line switching circuits
- Battery management application
- DC/DC converter applications

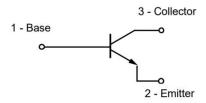
### Ordering Information

Device	Package	Shipping
SSCN8050SGS6	SOT-23	3000/Reel

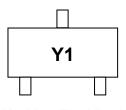
### Pin configuration



**SOT-23** 



**Circuit Diagram** 



Marking(Top View)



# **SSCN8050SGS6**

# ightharpoonup Absolute Maximum Ratings(T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	40	V
Collector- Emitter Voltage	V <sub>CEO</sub>	25	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Collector Current-Continuous	Ic	1500	mA
Collector Power Dissipation	Pc	1000	mW
Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>STG</sub>	-55 to 150	$^{\circ}$ C

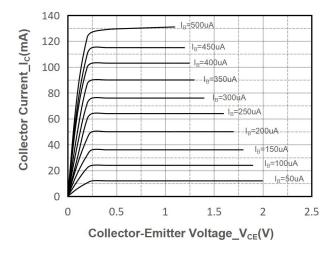
# ➤ Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

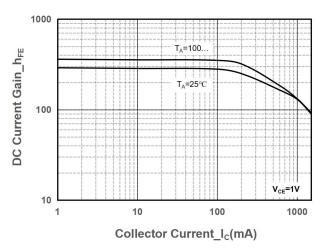
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	$I_C=0.1$ mA, $I_E=0$	40			V
Collector-emitter Breakdown Voltage	BV <sub>CEO</sub>	I <sub>C</sub> =1mA,I <sub>B</sub> =0	25			V
Emitter -Base Breakdown Voltage	BV <sub>EBO</sub>	I <sub>E</sub> =0.1mA,I <sub>C</sub> =0	5			V
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =35V,I <sub>E</sub> =0			0.1	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =4V,I <sub>C</sub> =0			0.1	μA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =1V,I <sub>C</sub> =100mA	85		400	
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =800mA,I <sub>B</sub> =80mA			0.5	V
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =800mA,I <sub>B</sub> =80mA			1.2	V
Transition fraguency	f⊤	V <sub>CE</sub> =6V,I <sub>C</sub> =20mA	150			MHz
Transition frequency		f=30MHz				IVIF1Z





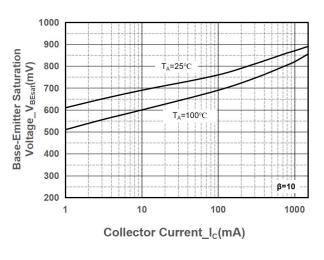
# > Typical Performance Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

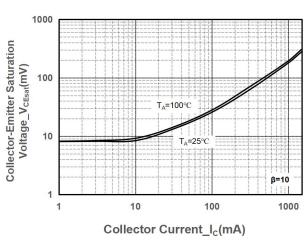




### **Collector Current vs. Collector-Emitter Voltage**

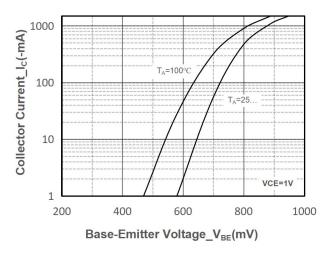
DC Current Gain vs. Collector Current

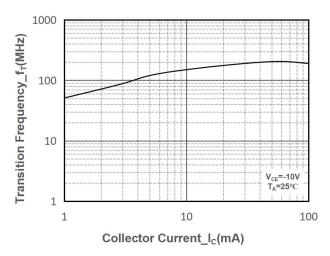




V<sub>BE(sat)</sub> vs. Collector Current

V<sub>CE(sat)</sub> vs. Collector Current



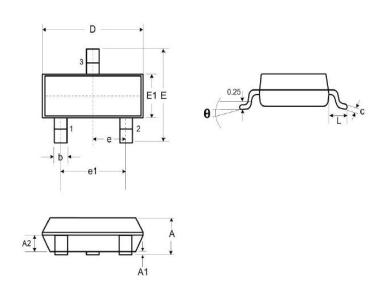


Collector Current vs. Base-Emitter Voltage

**Transition Frequency vs. Collector Current** 

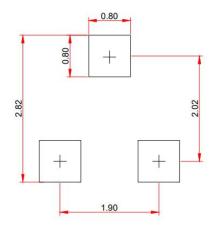


# Package Information



DIM	Millimeters			
	Min.	Тур.	Max.	
Α	0.89	-	1.12	
<b>A</b> 1	0.01	1	0.10	
A2	0.88	0.95	1.02	
b	0.30	-	0.51	
С	0.08	-	0.18	
D	2.80	2.90	3.04	
E	2.10	2.37	2.64	
E1	1.20	1.30	1.40	
e1		1.90		
е		0.95		
L	0.40	0.50	0.60	
L1	0.55			
N	3			
θ	0°	-	8°	

# Recommended Pad outline(Unit: mm)





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